

DRD410T22

Rectifier Diode

DS5997-1 March 2011 (LN28183)

FEATURES

- Double Side Cooling
- High Surge Capability

KEY PARAMETERS

V _{RRM}	2200V
I _{F(AV)}	410A
I _{FSM}	4900A



VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{RRM} V	Conditions
DRD410T22 DRD410T20 DRD410T18 DRD410T16	2200 2000 1800 1600	V _{RSM} = V _{RRM} +100V



ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD410T22 for a 2200V device

CURRENT RATINGS

 $T_{case} = 75^{\circ}C$ unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
I _{F(AV)}	Mean forward current	Half wave resistive load	490	А
I _{F(RMS)}	RMS value	-	770	А
IF	Continuous (direct) on-state current	-	690	А

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
I _{F(AV)}	Mean forward current	Half wave resistive load	410	А
I _{F(RMS)}	RMS value	-	640	А
I _F	Continuous (direct) on-state current	-	580	А

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 175^{\circ}C$	4.9	kA
l ² t	I ² t for fusing	$V_{R} = 0$	0.12	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Condition	5	Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.08	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Double side cooled	DC	-	0.02	°C/W
T _{vj}	Virtual junction temperature	Blocking V _{DRM} / _{VRRM}		-40	175	°C
T _{stg}	Storage temperature range			-40	175	°C
F _m	Clamping force			4	6	kN

CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V _{FM}	Forward voltage	At 800A peak, T _{case} = 25°C	-	1.85	V
I _{RM}	Peak reverse current	At V _{DRM,} T _{case} = 175°C	-	30	mA
Q _S Total stored charge	Total stored charge	I _F = 1000A, dI _{RR} /dt =10A/μs	-	1500	uС
	$T_{case} = 175^{\circ}C, V_{R} = 100V$			F -	
V _{TO}	Threshold voltage	At T _{vj} = 175°C	-	0.82	V
r _T	Slope resistance	At T _{vj} = 175°C	-	1.11	mΩ

CURVES





Fig.3 Dissipation curves



junction to case

PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

Some packages may be supplied with gate and or tags.

DRD410T22

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